

Small Signal Schottky Diode

Features

- Integrated protection ring against static discharge
- Very low forward voltage
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



94 9367

Applications

- Applications where a very low forward voltage is required

Mechanical Data

Case: DO35 Glass case

Weight: approx. 125 mg

Cathode Band Color: black

Packaging Codes/Options:

TR/10 k per 13" reel (52 mm tape), 50 k/box

TAP/10 k per Ammopack (52 mm tape), 50 k/box

Parts Table

Part	Ordering code	Type Marking	Remarks
BAT85S	BAT85S-TR or BAT85S-TAP	BAT85S	Tape and Reel/Ammopack

Absolute Maximum Ratings

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		V_R	30	V
Peak forward surge current	$t_p \leq 10\text{ ms}$	I_{FSM}	5	A
Repetitive peak forward current	$t_p \leq 1\text{ s}$	I_{FRM}	300	mA
Forward continuous current		I_F	200	mA
Average forward current	PCB mounting, $l = 4\text{ mm}$; $V_{RWM} = 25\text{ V}$, $T_{amb} = 50\text{ }^{\circ}\text{C}$	I_{FAV}	200	mA

Thermal Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Thermal resistance junction to ambient air	$l = 4\text{ mm}$, $T_L = \text{constant}$	R_{thJA}	350	K/W
Junction temperature		T_j	125	$^{\circ}\text{C}$
Storage temperature range		T_{stg}	- 65 to + 150	$^{\circ}\text{C}$

Electrical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Forward voltage	$I_F = 0.1\text{ mA}$	V_F			240	mV
	$I_F = 1\text{ mA}$	V_F			320	mV
	$I_F = 10\text{ mA}$	V_F			400	mV
	$I_F = 30\text{ mA}$	V_F			500	mV
	$I_F = 100\text{ mA}$	V_F			800	mV
Reverse current	$V_R = 25\text{ V}$	I_R			2	μA
Diode capacitance	$V_R = 1\text{ V}$, $f = 1\text{ MHz}$	C_D			10	pF
Reverse Recovery Time	$I_F = 10\text{ mA}$ to $I_R = 10\text{ mA}$ to $i_R = 1\text{ mA}$	t_{rr}			5	ns

Typical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

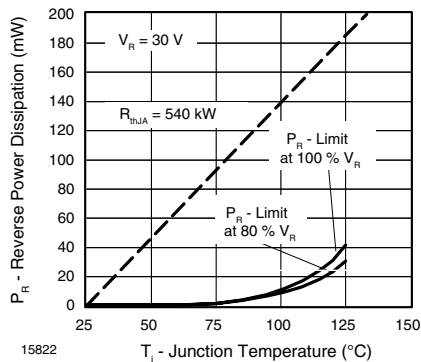


Figure 1. Max. Reverse Power Dissipation vs. Junction Temperature

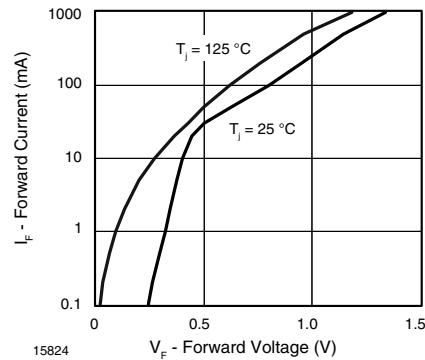


Figure 3. Forward Current vs. Forward Voltage

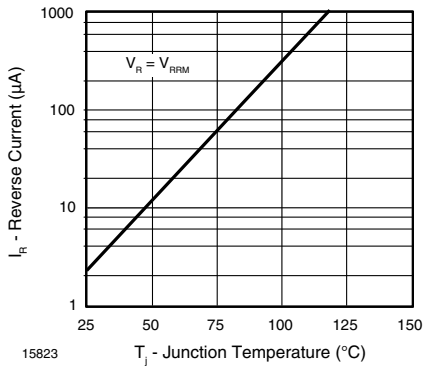


Figure 2. Reverse Current vs. Junction Temperature

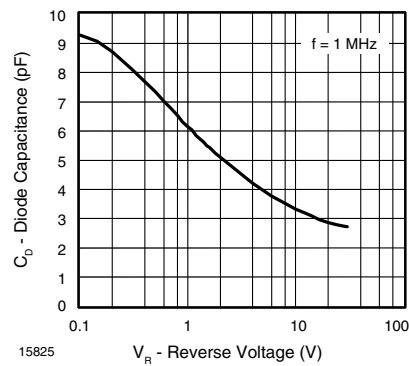


Figure 4. Diode Capacitance vs. Reverse Voltage

Package Dimensions in millimeters (inches): **DO35**